L Number	Hits	Search Text	DB	Time stamp
1	69435	silicon adj nitride	USPAT;	2004/01/14 17:33
			US-PGPUB	
2	4221	"Si.sub.3N.sub.4"	USPAT;	2004/01/14 17:34
		f	US-PGPUB	
3	1251900	opening\$1	USPAT;	2004/01/14 17:34
			US-PGPUB	
4	844838	hole\$1	USPAT;	2004/01/14 17:34
			US-PGPUB	
5	42426	trench\$2	USPAT;	2004/01/14 17:34
			US-PGPUB	
6	26206	wet adj etch\$3	USPAT;	2004/01/14 17:35
			US-PGPUB	
9	328	438/756.ccls.	USPAT;	2004/01/14 18:20
			US-PGPUB	
10	146	438/757.ccls.	USPAT;	2004/01/14 18:37
			US-PGPUB	
11	124	438/751.ccls.	USPAT;	2004/01/14 18:48
			US-PGPUB	
13	246	438/740.ccls.	USPAT;	2004/01/14 18:58
			US-PGPUB	
16	17204	etch\$3 adj stop\$4	USPAT;	2004/01/14 19:18
			US-PGPUB	
17	115	438/740.ccls. and (((silicon adj nitride) or "Si.sub.3N.sub.4") same	USPAT;	2004/01/14 19:18
		(etch\$3 adj stop\$4))	US-PGPUB	
18	59351	silicon adj oxide	USPAT;	2004/01/14 19:19
			US-PGPUB	
19	122089	"SiO.sub.2"	USPAT;	2004/01/14 19:19
•			US-PGPUB	
20	3	438/740.ccls. and ((wet adj etch\$3) same (etch\$3 adj stop\$4) same	USPAT;	2004/01/14 19:20
_		((silicon adj oxide) or "SiO.sub.2"))	US-PGPUB	
7	1485	((silicon adj nitride) or "Si.sub.3N.sub.4") same (opening\$1 or	USPAT;	2004/01/14 19:24
		hole\$1 or trench\$2) same (wet adj etch\$3)	US-PGPUB	